Dual 4-bit binary ripple counter Rev. 9 — 19 March 2024

1. General description

The 74HC393; 74HCT393 is a dual 4-stage binary ripple counter. Each counter features a clock input (nCP), an overriding asynchronous master reset input (nMR) and 4 buffered parallel outputs (nQ0 to nQ3). The counter advances on the HIGH-to-LOW transition of nCP. A HIGH on nMR clears the counter stages and forces the outputs LOW, independent of the state of nCP. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- Input levels:
 - For 74HC393: CMOS level
 - For 74HCT393: TTL level
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Two 4-bit binary counters with individual clocks
- Divide by any binary module up to 28 in one package
- Two master resets to clear each 4-bit counter individually

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC393D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads;	<u>SOT108-1</u>
74HCT393D	-		body width 3.9 mm	
74HC393PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	<u>SOT402-1</u>
74HCT393PW	-		body width 4.4 mm	
74HC393BQ	-40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced	<u>SOT762-1</u>
74HCT393BQ			very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm	

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4. Functional diagram

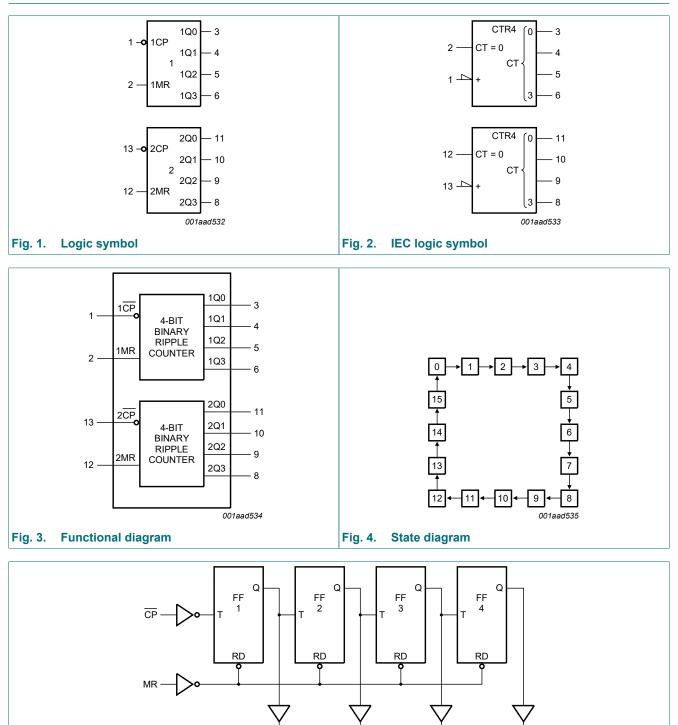


Fig. 5. Logic diagram (one counter)

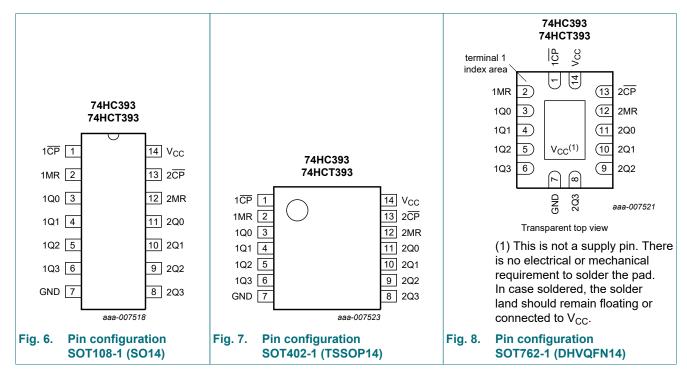
Q1

Q2

Q3 001aad536

Q0

5. Pinning information



5.1. Pinning

5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1 CP	1	clock input (HIGH-to-LOW, edge-triggered)
1MR	2	asynchronous master reset input (active HIGH)
1Q0, 1Q1, 1Q2, 1Q3	3, 4, 5, 6	flip-flop output
GND	7	ground (0 V)
2Q3, 2Q2, 2Q1, 2Q0	8, 9, 10, 11	flip-flop output
2MR	12	asynchronous master reset input (active HIGH)
2 CP	13	clock input (HIGH-to-LOW, edge-triggered)
V _{CC}	14	supply voltage

6. Functional description

Table 3. Count sequence for one counter

H = *HIGH* voltage level; *L* = *LOW* voltage level.

Count	Output			
	nQ0	nQ1	nQ2	nQ3
0	L	L	L	L
1	Н	L	L	L
2	L	Н	L	L
3	Н	Н	L	L
4	L	L	Н	L
5	Н	L	Н	L
6	L	Н	Н	L
7	Н	Н	Н	L
8	L	L	L	Н
9	Н	L	L	Н
10	L	Н	L	Н
11	н	Н	L	Н
12	L	L	Н	Н
13	н	L	Н	Н
14	L	Н	Н	Н
15	Н	Н	Н	Н

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _O	output current	$V_{\rm O}$ = -0.5 V to $V_{\rm CC}$ + 0.5 V	-	±25	mA
I _{CC}	supply current		-	±50	mA
I _{GND}	ground current		-	±50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[1]	-	500	mW

For SOT108-1 (SO14) package: P_{tot} derates linearly with 10.1 mW/K above 100 °C.
 For SOT402-1 (TSSOP14) package: P_{tot} derates linearly with 7.3 mW/K above 81 °C.
 For SOT762-1 (DHVQFN14) package: P_{tot} derates linearly with 9.6 mW/K above 98 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC393			74HCT393		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	
74HC39	3									
VIH	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
	V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V	
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1.0	-	±1.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

74HC_HCT393

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Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Мах	-
74HCT3	93									_
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	l _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1.0	-	±1.0	μA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	8.0	-	80	-	160	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 V;$ other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; I _O = 0 A								
		per input pin; nCP	-	40	144	-	180	-	196	μA
		per input pin; nMR	-	100	360	-	450	-	490	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit see Fig. 11.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max]
74HC393	3									
t _{pd}	propagation	nCP to nQ0; see <u>Fig. 9</u>	[1]							
	delay	V _{CC} = 2.0 V	-	41	125	-	155	-	190	ns
		V _{CC} = 4.5 V	-	15	25	-	31	-	38	ns
		V _{CC} = 5 V; C _L = 15 pF	-	12	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	12	21	-	26	-	32	ns
		nQx to nQ(x+1); see Fig. 9	[1]							
		V _{CC} = 2.0 V	-	14	45	-	55	-	70	ns
		V _{CC} = 4.5 V	-	5	9	-	11	-	14	ns
		V _{CC} = 5 V; C _L = 15 pF	-	5	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	4	8	-	9	-	12	ns

Dual 4-bit binary ripple counter

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{PHL}	HIGH to LOW	nMR to nQx; see <u>Fig. 10</u>								
	propagation	V _{CC} = 2.0 V	-	39	140	-	175	-	210	ns
	delay	V _{CC} = 4.5 V	-	14	28	-	35	-	42	ns
		V _{CC} = 5 V; C _L = 15 pF	-	11	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	11	24	-	30	-	36	ns
t _t	transition time	Qn; see <u>Fig. 9</u> [2]								
		V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t _W	pulse width	n CP HIGH or LOW; see <u>Fig. 9</u>								
		V _{CC} = 2.0 V	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	5	-	17	-	20	-	ns
		nMR HIGH; see <u>Fig. 10</u>								
		V _{CC} = 2.0 V	80	19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
t _{rec}	recovery time	nMR to nCP; see <u>Fig. 10</u>								
		V _{CC} = 2.0 V	5	3	-	5	-	5	-	ns
		V _{CC} = 4.5 V	5	1	-	5	-	5	-	ns
		V _{CC} = 6.0 V	5	1	-	5	-	5	-	ns
f _{clk(max)}	maximum	see Fig. 9								
. ,	clock	V _{CC} = 2.0 V	6	30	-	5	-	4	-	MHz
	frequency	V _{CC} = 4.5 V	30	90	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	99	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	107	-	28		24	-	MHz
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; \text{ f} = 1 \text{ MHz}; \qquad [3]$ V _I = GND to V _{CC}	-	23	-	-	-	-	-	pF
74HCT3	93									
t _{pd}	propagation	nCP to nQ0; see Fig. 9 [1]								
þa	delay	V _{CC} = 4.5 V	-	15	25	-	31	-	38	ns
		$V_{CC} = 5 V; C_1 = 15 pF$	-	20	-	-	-	-	_	ns
		nQx to nQ(x+1); see <u>Fig. 9</u> [1]								
		$V_{\rm CC} = 4.5 \rm V$	-	6	10	-	13	-	15	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	6	-	_	-	-	-	ns
t _{PHL}	HIGH to LOW	nMR to nQx; see <u>Fig. 10</u>								+
	propagation	$V_{\rm CC} = 4.5 V$	-	18	32	_	40	-	48	ns
	delay	$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	15	-	_	-	-	-	ns
t _t	transition time	Qn; see <u>Fig. 9</u> [2]								
		$V_{CC} = 4.5 V$ [2]	_	7	15	_	19	-	22	ns

Dual 4-bit binary ripple counter

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Мах	Min	Мах	Min	Max	1
t _W	pulse width	nCP HIGH or LOW; see Fig. 9								
		V _{CC} = 4.5 V	19	11	-	24	-	29	-	ns
		nMR HIGH; see <u>Fig. 10</u>								
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
t _{rec}	recovery time	nMR to nCP; see <u>Fig. 10</u>								
		V _{CC} = 4.5 V	5	0	-	5	-	5	-	ns
f _{clk(max)}	maximum	see <u>Fig. 9</u>								
	clock frequency	V _{CC} = 4.5 V	27	48	-	22	-	18	-	MHz
	licqueriey	V _{CC} = 5 V; C _L = 15 pF	-	53	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	C_L = 50 pF; f = 1 MHz; [3] V _I = GND to V _{CC} - 1.5 V	-	25	-	-	-	-	-	pF

 t_{pd} is the same as t_{PLH} and $t_{\text{PHL}}.$ [1]

[2]

 t_t is the same as t_{THL} and t_{TLH} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). [3]

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o = output$ frequency in MHz;

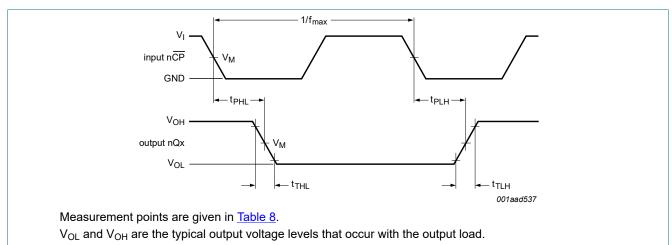
 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

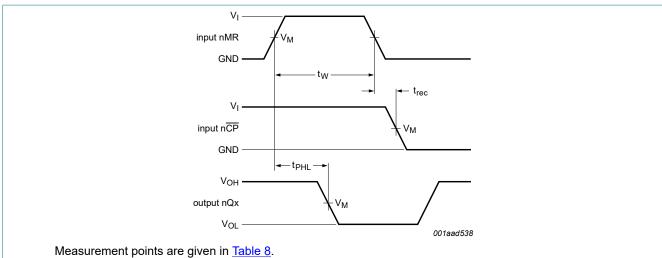
10.1. Waveforms and test circuit



Propagation delays clock (nCP) to output (nQx), the output transition times and the maximum clock Fig. 9. frequency

8/15

Dual 4-bit binary ripple counter

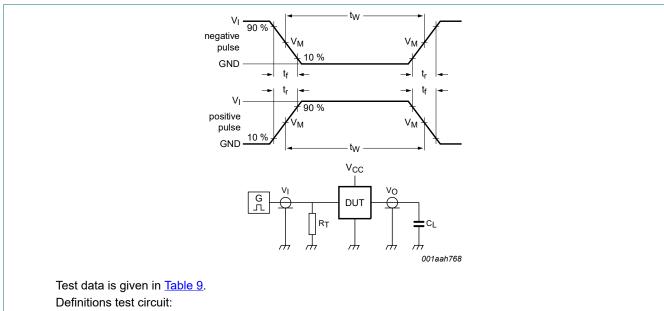


V_{OL} and V_{OH} are the typical output voltage levels that occur with the output load.

Fig. 10. Propagation delays clock (nCP) to output (nQx), pulse width master reset (nMR), and recovery time master reset (nMR) to clock (nCP)

Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC393	0.5V _{CC}	0.5V _{CC}
74HCT393	1.3 V	1.3 V



 R_T = termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = load capacitance including jig and probe capacitance.

Fig. 11. Test circuit for measuring switching times

Table 9. Test data

Туре	Input L		Load	Test
	VI	t _r , t _f	CL	
74HC393	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT393	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

11. Package outline

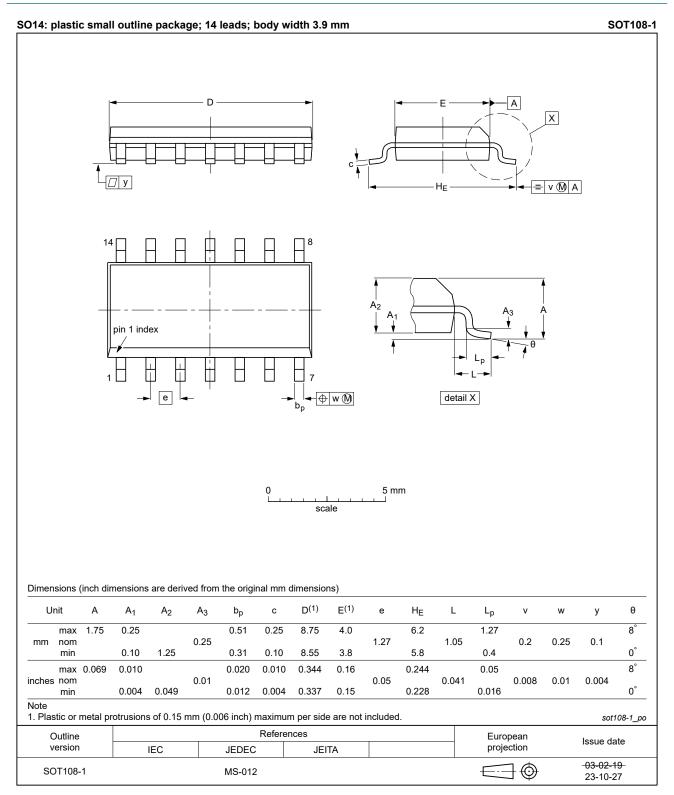


Fig. 12. Package outline SOT108-1 (SO14)

Dual 4-bit binary ripple counter

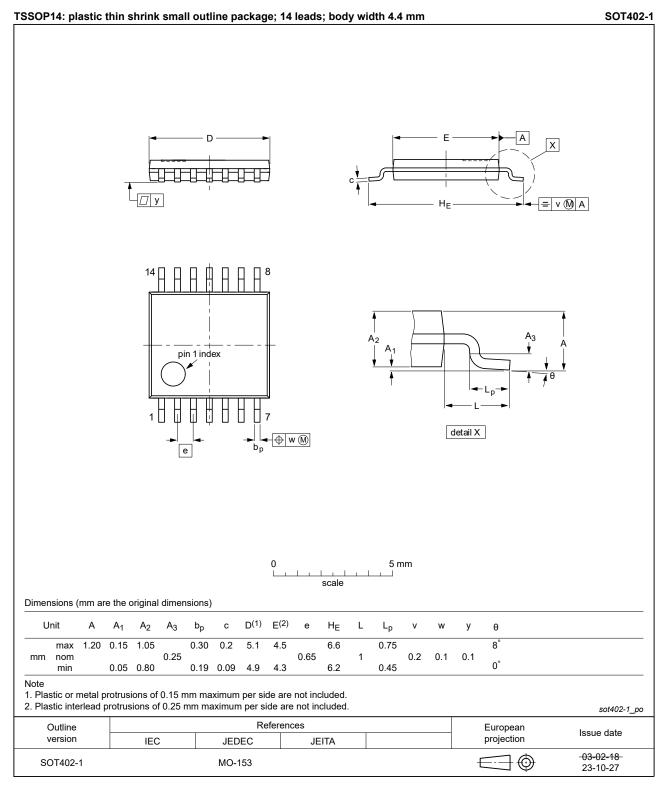


Fig. 13. Package outline SOT402-1 (TSSOP14)

Dual 4-bit binary ripple counter

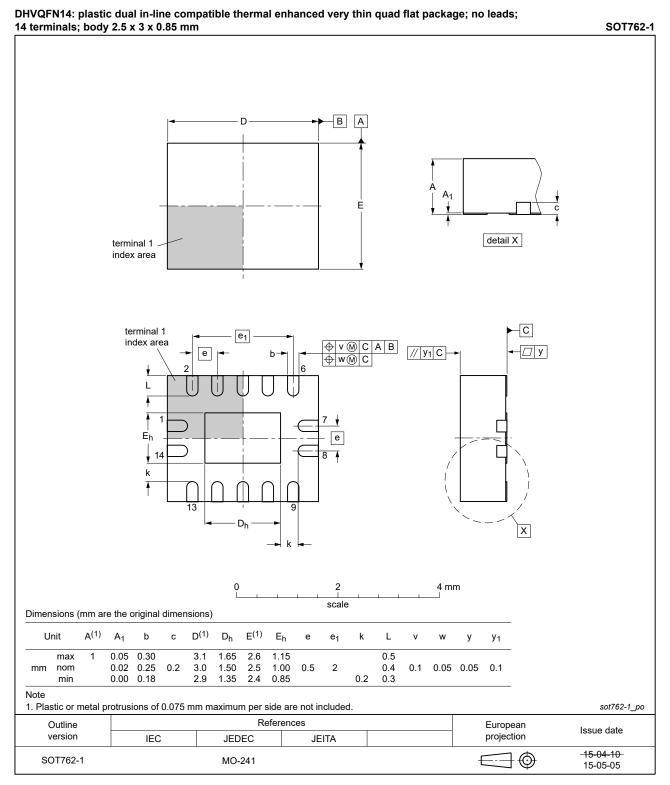


Fig. 14. Package outline SOT762-1 (DHVQFN14)

12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT393 v.9	20240319	Product data sheet	-	74HC_HCT393 v.8	
Modifications:	 Fig. 12, Fig. 13: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153. Section 2: ESD specification updated according to the latest JEDEC standard. 				
74HC_HCT393 v.8	20211022	Product data sheet	-	74HC_HCT393 v.7.1	
Modifications:	<u>Table 6</u> : V _{OH} and V _{OL} conditions for 74HCT393 corrected. (Errata)				
74HC_HCT393 v.7.1	20201021	Product data sheet	-	74HC_HCT393 v.6	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type numbers 74HC393DB and 74HCT393DB (SOT337-1/SSOP14) removed. <u>Section 1</u> (Errata) and <u>Section 2</u> updated. <u>Table 4</u>: Derating values for P_{tot} total power dissipation updated. v.7.1: <u>Table 6</u>: Values input leakage current for 74HC393 aligned with 74HCT393. (Errata) 				
74HC_HCT393 v.6	20151203	Product data sheet	-	74HC_HCT393 v.5	
Modifications:	Type numbers 74HC393N and 74HCT393N (SOT27-1) removed.				
74HC_HCT393 v.5	20140401	Product data sheet	-	74HC_HCT393 v.4	
Modifications:	• <u>Table 7</u> : The conditions for C _{PD} have been corrected (errata).				
74HC_HCT393 v.4	20130516	Product data sheet	-	74HC_HCT393 v.3	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 				
74HC_HCT393 v.3	20050906	Product data sheet	-	74HC_HCT393_CNV v.2	
74HC_HCT393_CNV v.2	19901201	Product specification	-	-	

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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